

# Standard Rectifier Module

$$V_{RRM} = 2 \times 1200 \text{ V}$$

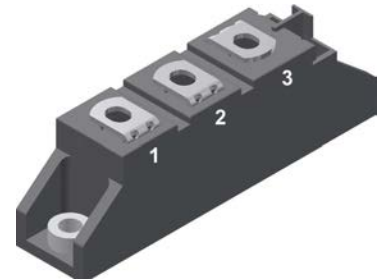
$$I_{FAV} = 99 \text{ A}$$

$$V_F = 1,22 \text{ V}$$

Phase leg

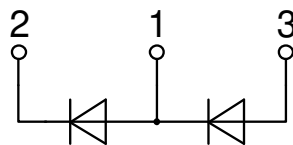
Part number

**MDD72-12N1B**



Backside: isolated

 E72873



## Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

## Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

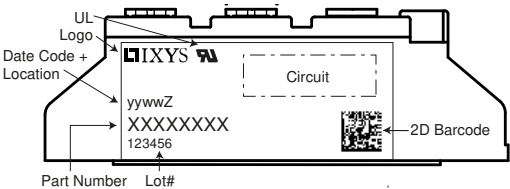
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| Rectifier    |                                                     |                                          |                                | Ratings |      |      |                   |
|--------------|-----------------------------------------------------|------------------------------------------|--------------------------------|---------|------|------|-------------------|
| Symbol       | Definition                                          | Conditions                               |                                | min.    | typ. | max. | Unit              |
| $V_{RSM}$    | <i>max. non-repetitive reverse blocking voltage</i> | $T_{VJ} = 25^{\circ}\text{C}$            |                                |         |      | 1300 | V                 |
| $V_{RRM}$    | <i>max. repetitive reverse blocking voltage</i>     | $T_{VJ} = 25^{\circ}\text{C}$            |                                |         |      | 1200 | V                 |
| $I_R$        | <i>reverse current</i>                              | $V_R = 1200\text{ V}$                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 200  | $\mu\text{A}$     |
|              |                                                     | $V_R = 1200\text{ V}$                    | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 15   | mA                |
| $V_F$        | <i>forward voltage drop</i>                         | $I_F = 150\text{ A}$                     | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1,27 | V                 |
|              |                                                     | $I_F = 300\text{ A}$                     |                                |         |      | 1,60 | V                 |
|              |                                                     | $I_F = 150\text{ A}$                     | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 1,22 | V                 |
|              |                                                     | $I_F = 300\text{ A}$                     |                                |         |      | 1,60 | V                 |
| $I_{FAV}$    | <i>average forward current</i>                      | $T_C = 100^{\circ}\text{C}$              | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 99   | A                 |
| $I_{F(RMS)}$ | <i>RMS forward current</i>                          | 180° sine                                |                                |         |      | 180  | A                 |
| $V_{F0}$     | <i>threshold voltage</i>                            | } <i>for power loss calculation only</i> | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 0,80 | V                 |
| $r_F$        | <i>slope resistance</i>                             |                                          |                                |         |      | 2,3  | m $\Omega$        |
| $R_{thJC}$   | <i>thermal resistance junction to case</i>          |                                          |                                |         |      | 0,35 | K/W               |
| $R_{thCH}$   | <i>thermal resistance case to heatsink</i>          |                                          |                                |         | 0,2  |      | K/W               |
| $P_{tot}$    | <i>total power dissipation</i>                      |                                          | $T_C = 25^{\circ}\text{C}$     |         |      | 357  | W                 |
| $I_{FSM}$    | <i>max. forward surge current</i>                   | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 1,70 | kA                |
|              |                                                     | t = 8,3 ms; (60 Hz), sine                | $V_R = 0\text{ V}$             |         |      | 1,84 | kA                |
|              |                                                     | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 1,45 | kA                |
|              |                                                     | t = 8,3 ms; (60 Hz), sine                | $V_R = 0\text{ V}$             |         |      | 1,56 | kA                |
| $I^2t$       | <i>value for fusing</i>                             | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 14,5 | kA <sup>2</sup> s |
|              |                                                     | t = 8,3 ms; (60 Hz), sine                | $V_R = 0\text{ V}$             |         |      | 14,0 | kA <sup>2</sup> s |
|              |                                                     | t = 10 ms; (50 Hz), sine                 | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 10,4 | kA <sup>2</sup> s |
|              |                                                     | t = 8,3 ms; (60 Hz), sine                | $V_R = 0\text{ V}$             |         |      | 10,1 | kA <sup>2</sup> s |
| $C_J$        | <i>junction capacitance</i>                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$   | $T_{VJ} = 25^{\circ}\text{C}$  |         | 116  |      | pF                |

| Package TO-240AA     |                                                              |                      |                                         | Ratings |      |      |      |
|----------------------|--------------------------------------------------------------|----------------------|-----------------------------------------|---------|------|------|------|
| Symbol               | Definition                                                   | Conditions           |                                         | min.    | typ. | max. | Unit |
| I <sub>RMS</sub>     | RMS current                                                  | per terminal         |                                         |         |      | 200  | A    |
| T <sub>VJ</sub>      | virtual junction temperature                                 |                      |                                         | -40     |      | 150  | °C   |
| T <sub>op</sub>      | operation temperature                                        |                      |                                         | -40     |      | 125  | °C   |
| T <sub>stg</sub>     | storage temperature                                          |                      |                                         | -40     |      | 125  | °C   |
| Weight               |                                                              |                      |                                         |         | 76   |      | g    |
| M <sub>D</sub>       | mounting torque                                              |                      |                                         | 2,5     |      | 4    | Nm   |
| M <sub>T</sub>       | terminal torque                                              |                      |                                         | 2,5     |      | 4    | Nm   |
| d <sub>Spp/App</sub> | creepage distance on surface   striking distance through air | terminal to terminal | 13,0                                    | 9,7     |      |      | mm   |
| d <sub>Spb/Apb</sub> |                                                              | terminal to backside | 16,0                                    | 16,0    |      |      | mm   |
| V <sub>ISOL</sub>    | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA | 4800    |      |      | V    |
|                      |                                                              | t = 1 minute         |                                         | 4000    |      |      | V    |



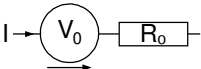
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MDD72-12N1B     | MDD72-12N1B        | Box           | 36       | 453188   |

| Similar Part | Package  | Voltage class |
|--------------|----------|---------------|
| MDD72-08N1B  | TO-240AA | 800           |
| MDD72-14N1B  | TO-240AA | 1400          |
| MDD72-16N1B  | TO-240AA | 1600          |
| MDD72-18N1B  | TO-240AA | 1800          |

Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 150^{\circ}\text{C}$



Rectifier

$V_{0 \text{ max}}$

$R_{0 \text{ max}}$

threshold voltage

slope resistance \*

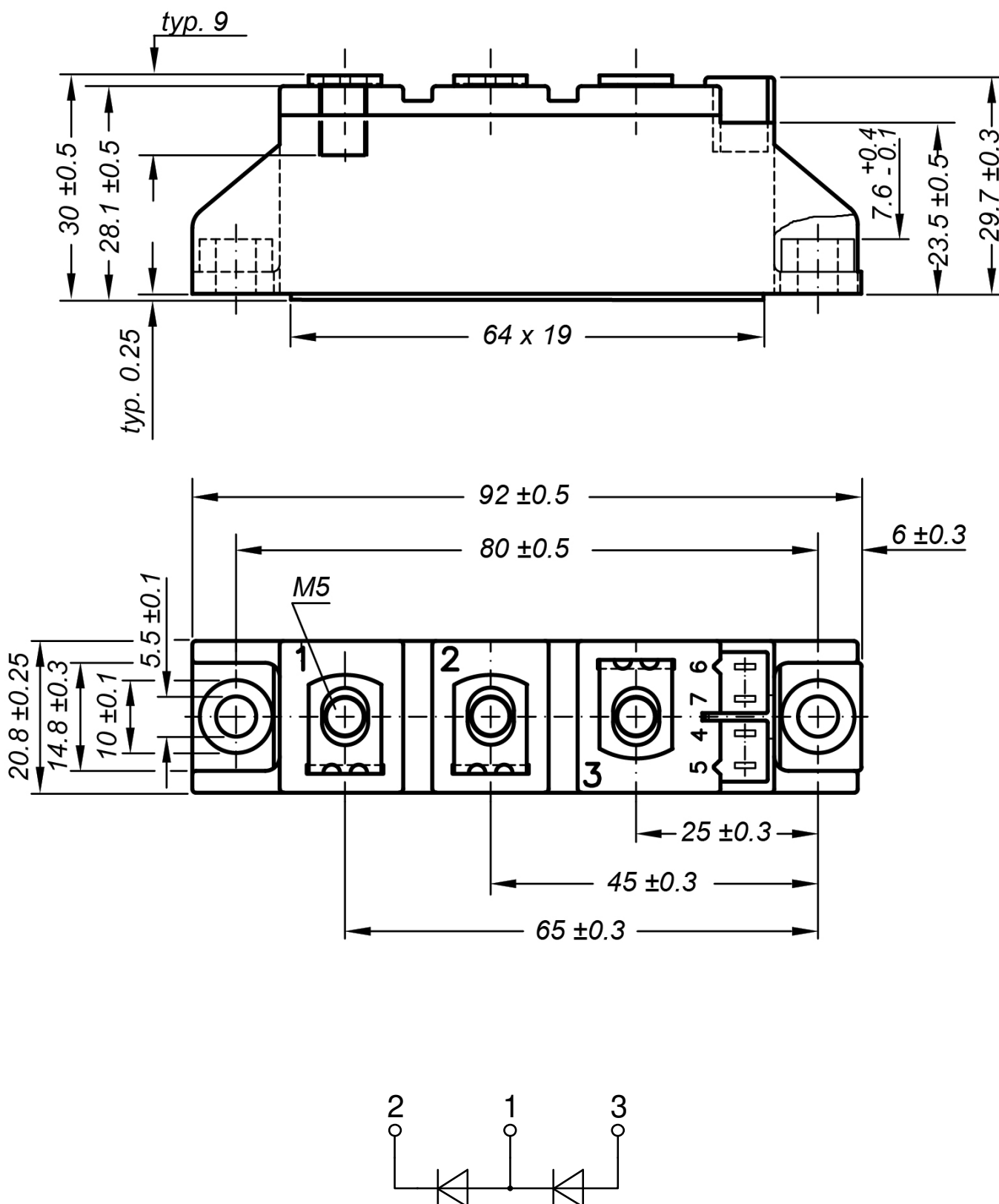
0,8

1,1

V

mΩ

Outlines TO-240AA



## Rectifier

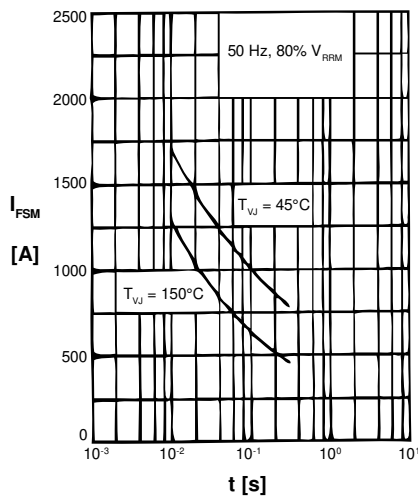


Fig. 1 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value,  $t$ : duration

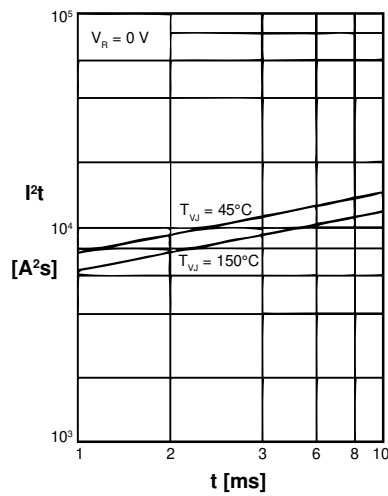


Fig. 2  $I^2t$  versus time (1-10 ms)

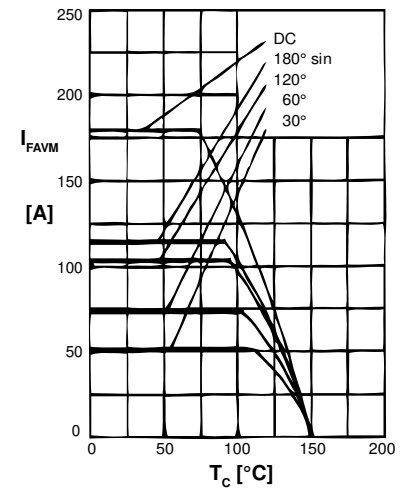


Fig. 3 Maximum forward current at case temperature

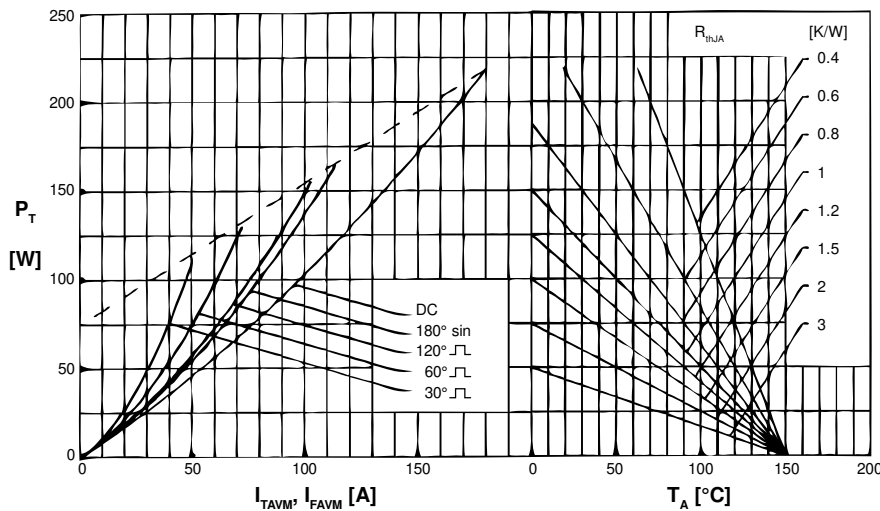


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per diode)

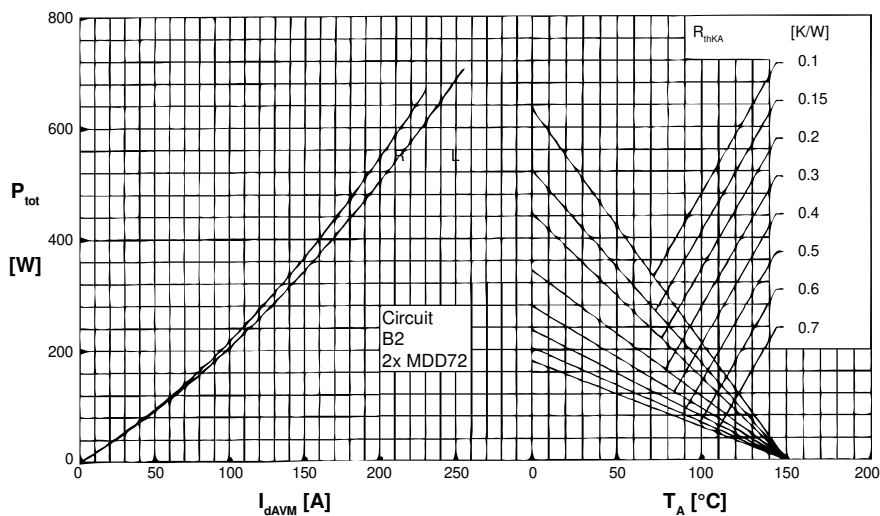


Fig. 6 Single phase rectifier bridge: Power dissipation versus direct output current and ambient temperature; R = resistive load, L = inductive load

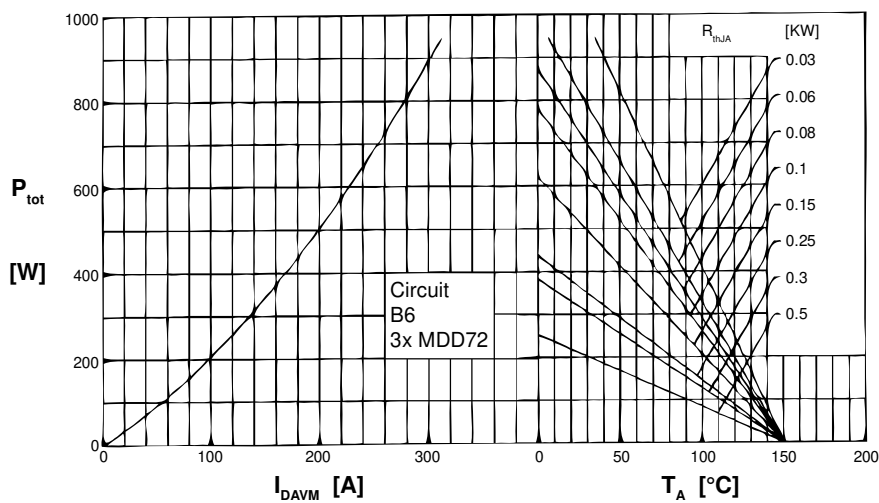
**Rectifier**


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

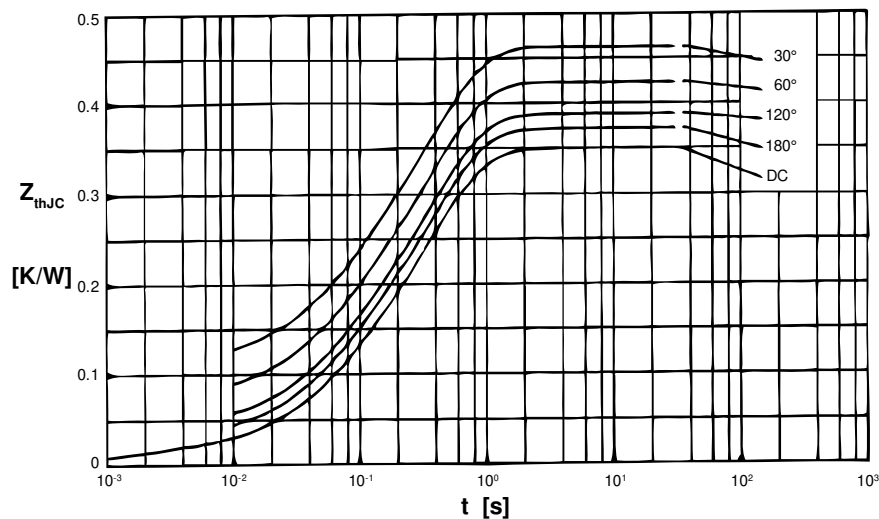


Fig. 7 Transient thermal impedance junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

| d    | $R_{thJC}$ [K/W] |
|------|------------------|
| DC   | 0.35             |
| 180° | 0.37             |
| 120° | 0.39             |
| 60°  | 0.43             |
| 30°  | 0.47             |

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ [K/W] | $t_i$ [s] |
|---|-----------------|-----------|
| 1 | 0.013           | 0.0014    |
| 2 | 0.072           | 0.0620    |
| 3 | 0.265           | 0.3750    |

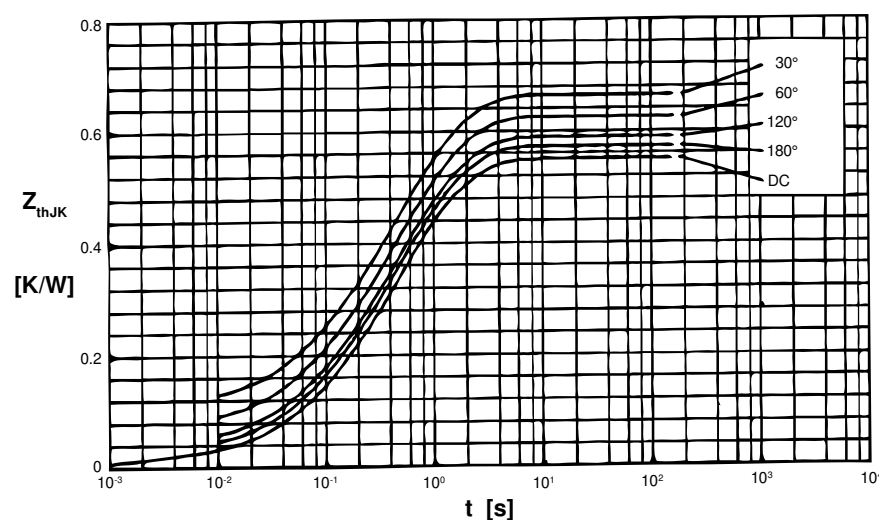


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJK}$  for various conduction angles d:

| d    | $R_{thJK}$ [K/W] |
|------|------------------|
| DC   | 0.55             |
| 180° | 0.57             |
| 120° | 0.59             |
| 60°  | 0.63             |
| 30°  | 0.67             |

Constants for  $Z_{thJK}$  calculation:

| i | $R_{thi}$ [K/W] | $t_i$ [s] |
|---|-----------------|-----------|
| 1 | 0.013           | 0.0014    |
| 2 | 0.072           | 0.0620    |
| 3 | 0.265           | 0.3750    |
| 4 | 0.200           | 1.3200    |